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MM74HCT245 Octal 3-STATE Transceiver

General Description

The MM74HCT245 3-STATE bi-directional buffer utilizes advanced silicon-gate CMOS technology and is intended for two-way asynchronous communication between data buses. It has high drive current outputs which enable high speed operation even when driving large bus capacitances. This circuit possesses the low power consumption of CMOS circuitry, yet has speeds comparable to low power Schottky TTL circuits.

This device is TTL input compatible and can drive up to 15 LS-TTL loads, and all inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

The MM74HCT245 has one active low enable input (\overline{G}) , and a direction control (DIR). When the DIR input is HIGH, data flows from the A inputs to the B outputs. When DIR is LOW, data flows from B to A.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug-in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

Features ■ TTL input compatible

- 3-STATE outputs for connection to system busses
- High output drive current: 6 mA (min)
- High speed: 16 ns typical propagation delay
- Low power: 80 µA (74HCT Series)

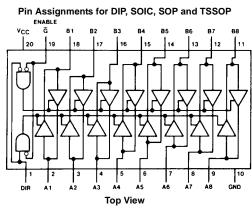
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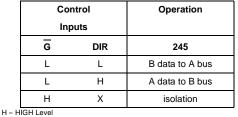
Order Number	Package Number	Package Description	
MM74HCT245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide	
MM74HCT245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide	
MM74HCT245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide	
MM74HCT245N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide	
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.			

Connection Diagram

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Truth Table

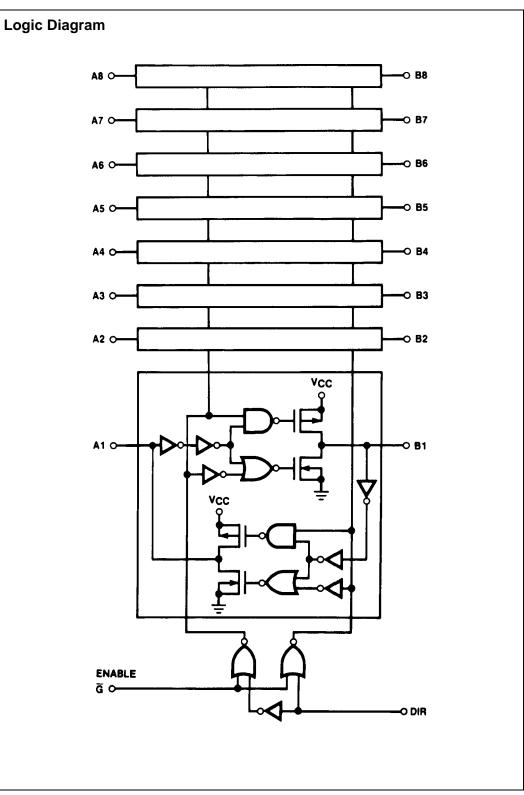




L = LOW Level X = Irrelevant

DS005366





Absolute Maximum Ratings(Note 1)

-0.5 to +7.0V
–1.5 to V_{CC} +1.5V
–0.5 to V_{CC} +0.5V
±20 mA
±35 mA
±70 mA
–65°C to +150°C
600 mW
500 mW
260°C

Recommended Operating Conditions

	Min	Max	Units		
Supply Voltage (V _{CC})	4.5	5.5	V		
DC Input or Output Voltage					
(V _{IN} , V _{OUT})	0	V _{CC}	V		
Operating Temperature Range (T _A)	-40	+85	°C		
Input Rise or Fall Times					
(t _r , t _f)		500	ns		
Note 1: Absolute Maximum Ratings are those values beyond which dam-					

MM74HCT245

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics

(V_{CC} = 5V \pm 10%, unless otherwise specified.) $T_A=25^\circ C$ T_A = -40 to 85°C T_A = -55 to 125°C Symbol Parameter Conditions Units Guaranteed Limits Тур VIH Minimum HIGH Level 2.0 2.0 V 2.0 Input Voltage Maximum LOW Level V_{IL} 0.8 0.8 0.8 V Input Voltage V_{OH} Minimum HIGH Level $V_{IN} = V_{IH} \text{ or } V_{IL}$ $|I_{OUT}| = 20 \ \mu A$ $V_{\rm CC}$ V_{CC}- 0.1 Output Voltage V_{CC}- 0.1 V_{CC}- 0.1 V |I_{OUT}| = 6.0 mA, V_{CC} = 4.5V 4.2 3.98 3.84 3.7 V $|I_{OUT}| = 7.2 \text{ mA}, V_{CC} = 5.5 \text{V}$ 5.2 ٧ 4.98 4.84 4.7 Maximum LOW Level V_{OL} $V_{IN} = V_{IH} \text{ or } V_{IL}$ Voltage $|I_{OUT}| = 20 \ \mu A$ 0.1 0.1 V 0 0.1 |I_{OUT}| = 6.0 mA, V_{CC} = 4.5V 0.2 0.26 0.33 0.4 V $|I_{OUT}| = 7.2 \text{ mA}, V_{CC} = 5.5 \text{V}$ 0.2 0.26 0.33 0.4 V $V_{IN} = V_{CC} \text{ or } GND,$ Maximum Input ±0.1 ±1.0 ±1.0 μA IIN V_{IH} or V_{IL} , Pin 1 or 19 Current $V_{OUT} = V_{CC} \text{ or } GND$ Maximum 3-STATE ±0.5 ±5.0 ±10 μΑ I_{OZ} $\overline{G} = V_{IH}$ Output Leakage Current Maximum Quiescent $V_{IN} = V_{CC} \text{ or } GND$ 80 160 I_{CC} 8 μA Supply Current $I_{OUT} = 0 \ \mu A$ V_{IN} = 2.4V or 0.5V (Note 4) 0.6 1.0 1.3 1.5 mΑ

Note 4: Measured per input. All other inputs at V_{CC} or ground.

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AC Electrical Characteristics

$V_{CC} = 5.0V, t_{r} =$	t _f = 6 ns, T _A = 25°C (unl	ess otherwise specified)	

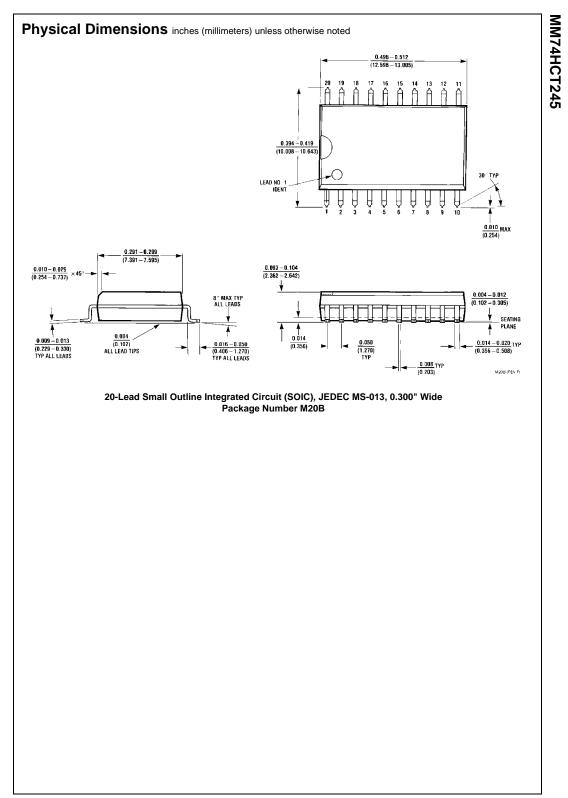
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Output	C _L = 45 pF	16	20	ns
	Propagation Delay				
t _{PZL} , t _{PZH}	Maximum Output	C _L = 45 pF	29	40	ns
	Enable Time	$R_L = 1 \ k\Omega$			
t _{PLZ} , t _{PHZ}	Maximum Output	C _L = 5 pF	20	25	ns
	Disable Time	$R_L = 1 \ k\Omega$			

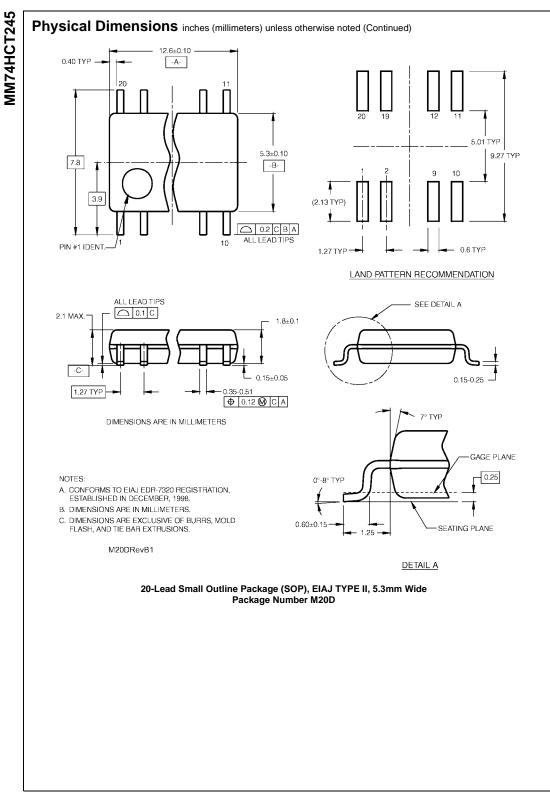
AC Electrical Characteristics

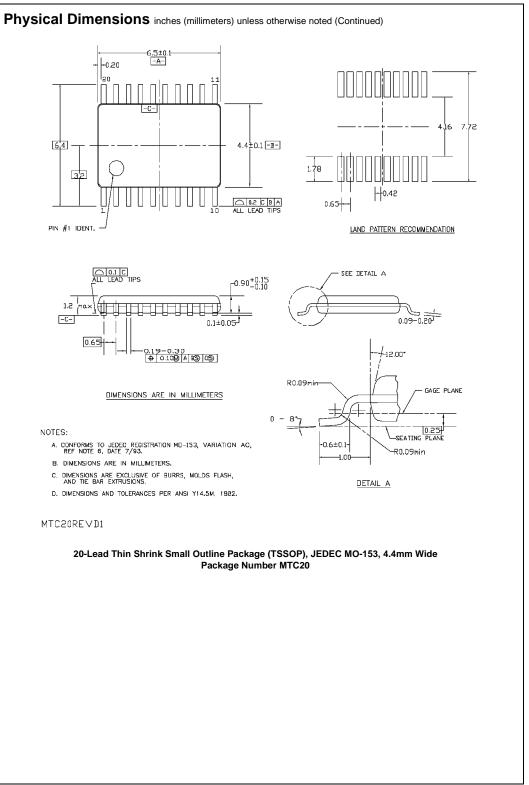
 V_{CC} = 5.0V \pm 10%, t_r = t_f = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	T _A =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units	
	raiameter		Тур	Typ Guaranteed Limits				
t _{PHL} , t _{PLH}	Maximum Output	C _L = 50 pF	17	23	29	34	ns	
	Propagation Delay	C _L = 150 pF	24	30	38	45	ns	
t _{PZL}	Maximum Output	$R_L = 1 k\Omega$	31	42	53	63	ns	
	Enable Time	$C_L = 50 \text{ pF}$						
t _{PZH}	Maximum Output	$R_L = 1 k\Omega$	23	33	41	49	ns	
	Enable Time	$C_L = 50 \text{ pF}$						
t _{PHZ} , t _{PLZ}	Maximum Output	$R_L = 1 k\Omega$	21	30	38	45	ns	
	Disable Time	C _L = 50 pF						
t _{THL} , t _{TLH}	Maximum Output	$C_L = 50 \text{ pF}$	8	12	15	18	ns	
	Rise and Fall Time							
C _{IN}	Maximum Input		10	15	15	15	pF	
	Capacitance							
C _{OUT}	Maximum Output/Input		20	25	25	25	pF	
	Capacitance							
C _{PD}	Power Dissipation	$\overline{G} = V_{CC}$ (Note 5)	7				pF	
	Capacitance	G = GND	100				pF	

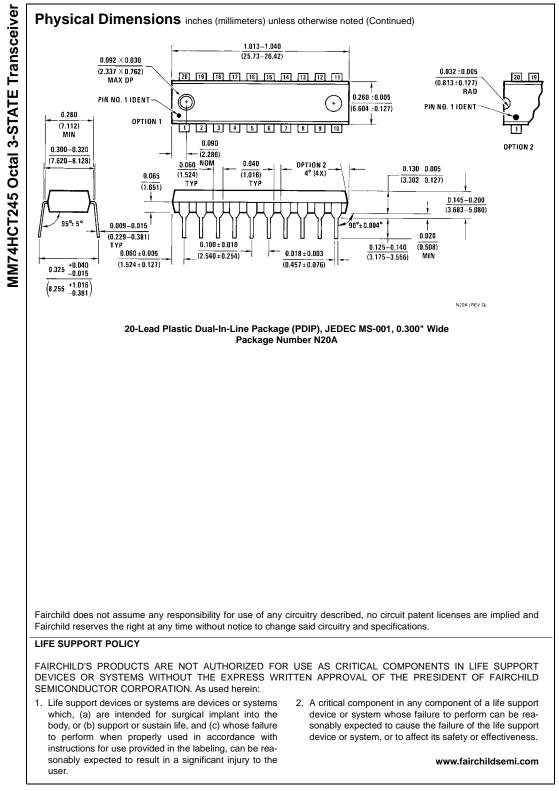
Note 5: C_{PD} determines the no load power consumption, $P_D = C_{PD} V_{CC} 2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.







MM74HCT245



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